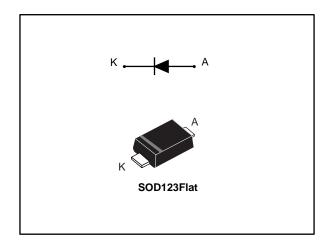


# STPS2H100ZFY

# Automotive high voltage power Schottky rectifier

Datasheet - production data



#### **Features**



- AEC-Q101 qualified
- High junction temperature capability
- Low leakage current
- Negligible switching losses
- Avalanche capability specified
- ECOPACK®2 compliant component
- PPAP capable

### **Description**

Single chip Schottky rectifiers suited to automotive applications, such as lighting, diesel injection, or engine control unit.

Packaged in SOD123Flat, this device is especially intended for surface mounting and used in high frequency converters, free wheeling and reverse polarity protection in automotive applications.

**Table 1: Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	2 A
V <sub>RRM</sub>	100 V
V <sub>F</sub> (typ.)	0.65 V
T <sub>j</sub> (max.)	175 °C

This is information on a product in full production.

Characteristics STPS2H100ZFY

### 1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage $T_j = -40 \text{ °C to } +175 \text{ °C}$		100	V
I <sub>F(AV)</sub>	Average forward current $\delta$ = 0.5, square wave $T_L = 140  ^{\circ}\text{C}$		2	А
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		50	Α
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 10 \mu s, T_j = 125 ^{\circ} C$		105	W
T <sub>stg</sub>	Storage temperature range		-65 to +175	°C
Tj	Operating junction temperature range <sup>(1)</sup>		-40 to +175	C

#### Notes:

**Table 3: Thermal parameters** 

Symbol	Parameter	Max. value	Unit
R <sub>th(j-l)</sub>	Junction to lead	20	°C/W

**Table 4: Static electrical characteristics** 

Symbol	Parameter	Test cor	nditions	Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Poverse leekage gurrent	T <sub>j</sub> = 25 °C	C ,, ,,	ı		1	μΑ
IR	Reverse leakage current	$T_j = 125  ^{\circ}\text{C}$ $V_R = V_{RRM}$	ı	0.2	0.5	mA	
		T <sub>j</sub> = 25 °C		•		0.86	
V <sub>F</sub> <sup>(2)</sup>	Commend walters draw	$T_{j} = 125  ^{\circ}\text{C}$ IF = 2 A	IF = Z A	-	0.65	0.70	V
VF(=)	V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	F = 4 A	ı		0.96	V
		T <sub>j</sub> = 125 °C		ı	0.75	0.83	

#### Notes:

 $^{(1)}$ Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2%

(2)Pulse test:  $t_p$  = 380 μs, δ < 2%

To evaluate the conduction losses, use the following equation:

 $P = 0.57 \times I_{F(AV)} + 0.065 \times I_{F^{2}(RMS)}$ 

For more information, please refer to the following application notes related to the power losses.

- AN604 (Calculation of conduction losses in a power rectifier)
- AN4021 (Calculation of reverse losses in a power diode)

 $<sup>^{(1)}(</sup>dP_{tot}/dT_j) < (1/R_{th(j-a)}) \ condition \ to \ avoid \ thermal \ runaway \ for \ a \ diode \ on \ its \ own \ heatsink.$ 

STPS2H100ZFY Characteristics

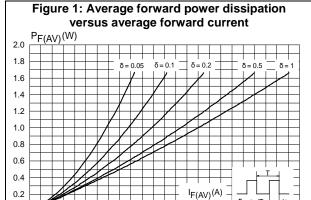
 $\delta_i = tp/T$ 

1.2 1.4 1.6 1.8 2.0 2.2 2.4

### 1.1 Characteristics (curves)

0.0

0.0



1.0

Figure 2: Average forward current versus ambient temperature ( $\delta = 0.5$ )  $I_{F(AV)}(A)$  $R_{th(j-a)} = R_{th(j-l)}$ 6 5 3 2 T<sub>amb</sub>(°C) 0 25 50 75 100 0 125 175

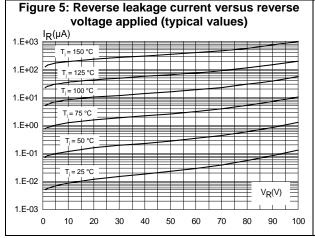
Figure 3: Normalized avalanche power derating versus pulse duration (T<sub>j</sub> = 125 °C)

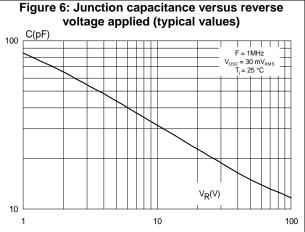
1 PARM(10 µS)

0.01

1 10 100 1000

Figure 4: Relative variation of thermal impedance junction to lead versus pulse duration Z<sub>th(j-I)</sub>/R<sub>th(j-I)</sub> 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 tp(s) 0.0 1.E-04 1.E-03 1.E-01





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Figure 7: Forward voltage drop versus forward current (typical values) I<sub>F</sub>(A) 10.00 T<sub>i</sub> = 75 °C 1.00 0.10 0.01 0.0 0.1 0.2 0.3 0.6 0.7 0.9 1.0 1.1

versus copper surface under each lead (typical values) R<sub>th(j-a)</sub>(°C/W) 250 200 150 100 Epoxy printed board FR4,  $e_{Cu}$  = 35  $\mu m$ 50  $S_{Cu}(cm^2)$ 0.5 1.0 2.0 2.5 3.0 0.0 1.5 3.5 4.0 4.5 5.0

Figure 8: Thermal resistance junction to ambient

STPS2H100ZFY Package information

## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

### 2.1 SOD123Flat package information

Figure 9: SOD123Flat package outline

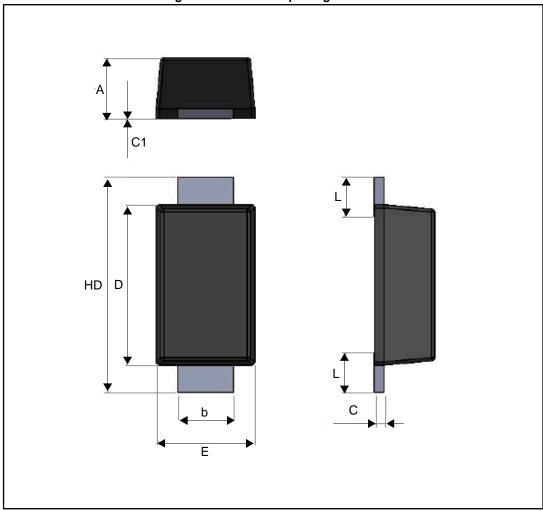
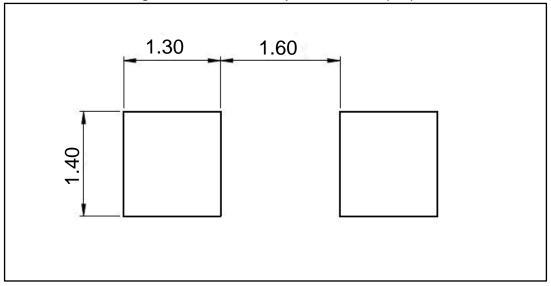


Table 5: SOD123Flat package mechanical data

	Dimensions			
Ref.	Millimeters			
	Min.	Тур.	Max.	
А	0.86	0.98	1.10	
b	0.80	0.90	1.00	
С	0.08	0.15	0.25	
c1	0.00		0.10	
D	2.50	2.60	2.70	
Е	1.50	1.60	1.80	
HD	3.30	3.50	3.70	
L	0.45	0.65	0.85	

Figure 10: SOD123Flat footprint dimensions (mm)



# 3 Ordering information

**Table 6: Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS2H100ZFY	2Y1	SOD123Flat	12.5 mg	3000	Tape and reel

# 4 Revision history

**Table 7: Document revision history** 

Date	Revision	Changes
20-Oct-2016	1	Initial release.



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